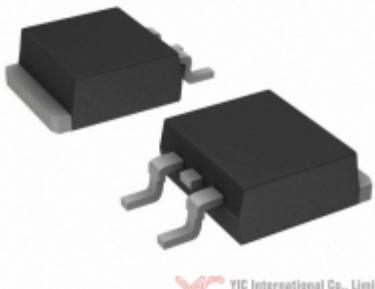

	FQB12P10TM	
	Hersteller-Teilenummer:	FQB12P10TM
	Hersteller / Marke:	AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung:	MOSFET P-CH 100V 11.5A D2PAK
<p>Image may be representation. See specs for product details.</p>	Datenblätter:	 FQB12P10TM.pdf
	RoHs Status:	Bleifrei / RoHS-konform
	Lagerzustand:	New original, 32363 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS

Spezifikationen

Teilenummer	FQB12P10TM
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET P-CH 100V 11.5A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	32363 pcs Stock
detaillierte Beschreibung	P-Channel 100V 11.5A (Tc) 3.75W (Ta), 75W (Tc)
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D ² PAK (TO-263AB)
Verlustleistung (max)	3.75W (Ta), 75W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	11.5A (Tc)
Rds On (Max) @ Id, Vgs	290 mOhm @ 5.75A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	27nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	800pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)



















































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Sie können auch interessiert sein:

 FQB12N60TM Fairchild/ON Semiconductor FQB12N60TM FAIRCHILD	 FQB12N60TM_AM002 Fairchild/ON Semiconductor MOSFET N-CH 600V 10.5A D2PAK	 Not Actual Photo YIC International Co., Limited. FQB12P20 FSC FQB12P20 FSC	 FQB12P20TM AMI Semiconductor / ON Semiconductor MOSFET P-CH 200V 11.5A D2PAK
 FQB12P10TM Fairchild/ON Semiconductor MOSFET P-CH 100V 11.5A D2PAK	 FQB12P20TM Fairchild/ON Semiconductor MOSFET P-CH 200V 11.5A D2PAK	 Not Actual Photo YIC International Co., Limited. FQB13N06L F FQB13N06L F	 Not Actual Photo YIC International Co., Limited. FQB12P10 FSC FQB12P10 FSC

heiße Teile

Mehr

 FQB10N50CFTM_WS	 FQB10N60C	 FQB10N60CTM	 D FQB10N60CTM	 FQB11N40
 FQB11N40C	 FQB11N40CTM	 D FQB11N40CTM	 FQB11N60FTM	 FQB11N60TM
 FQB11P06	 FQB11P06TM	 FQB11P06TM	 FQB11P06TM**CN-SCI	 FQB12N50TM
 D FQB12N50TM_AM002	 FQB12N50TM_AM002	 FQB12N60	 FQB12N60C	 FQB12N60CTM
 FQB12N60CTM	 FQB12N60TM	 FQB12N60TM_AM002	 FQB12N60TM_AM002	 FQB12P10
 FQB12P10TM	 FQB12P20	 D FQB12P20TM	 FQB12P20TM	 FQB13N06L
 FQB13N10	 D FQB13N10L	 FQB13N50	 FQB13N50CTM	 FQB13N50CTM
 FQB140N03L	 FQB14N30TM	 FQB14N30TM	 FQB16N25TM	 FQB16N25TM
 FQB17P06	 FQB17P10	 FQB17P10TM	 D FQB17P10TM	 FQB19N10L
 FQB19N10LTM	 FQB19N10LTM	 FQB19N10TM	 FQB19N10TM	 FQB19N20

Contact us:Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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